		Sneet 1 of 4
FORM PTO-1449	Atty. Docket No.: S01.12-0978	Appl. No.:
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	First Named Invent	or:
	Ear C. Johns	
	Filing Date	Group Art:
	Herewith	

U.S. PATENT DOCUMENTS

Exam: Init		Document No.	Date	Name	Class	Sub Class	Filing Date If Appropriate
/JO/	AA	3,703,328	11/1972	Glass et al.	350	3.5	:
	AB	3,940,750	2/1976	Voegeli	340	174	
	AC	4,041,477	8/1977	Drenckhan	340	173	
	AD	4,099,247	7/1978	Mikada et al.	364	710	
	AE	4,103,341	7/1978	Brody	365	117	·
	AF	4,153,328	5/1979	Wang	350	96.11	
	AG	4,187,109	2/1980	Mageumi et al.	430	2	
	АН	4,195,355	3/1980	Rohrer	365	145	
	AI	4,220,395	9/1980	Wang et al.	350	96.12	
	AJ	4,319,355	3/1982	Mollier	371	21	
	AK	4,344,155	8/1982	Mollier	365	200	
	AL	4,551,819	11/1985	Michl et al.	365	120	
	AM ·	4,649,519	3/1987	Sun et al.	365	122	
	AN	4,731,754	3/1988	Ogden et al.	365	121	
	AO	4,794,560	12/1988	Bell et al.	365	122	
V	AP	4,832,456	5/1989	Yamazaki et al.	350	334	
/JO/	AQ	4,858,040	8/1989	Hazebrouck	360	78.05	

FOREIGN PATENT DOCUMENTS

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Exami Init		Document No.	Date	Name	Class	Sub Class	Filing Date If Appropriate
/JO/	ва	4,927,220	5/1990	Hesselink et al.	350	3.64	
	BB	4,954,951	9/1990	Hyatt	364	200	
	вс	4,956,784	9/1990	Hadavi et al.	364	468	
	BD	4,977,540	12/1990	Goodwin et al.	365	49	
	BE	4,988,891	1/1991	Mashiko	307	201	
	BF	5,004,309	4/1991	Caulfield et al.	350	3.68	
	BG	5,005,927	4/1991	Cudney et al.	350	3.64	
	вн	5,014,235	5/1991	Morton	364	900	
	BI	5,051,950	1/1991	Evans, Jr. et al.	365	109	
	BJ	5,132,811	7/1992	Iwaki et al.	359	6	
	вк	5,132,813	7/1992	Caulfield et al.	359	11	
	BL	5,151,822	9/1992	Hekker et al.	359	559	
	ВМ	5,175,775	12/1992	Iwaki et al.	382	31	
	BN	5,179,533	1/1993	Bullington et al.	365	110	
	ВО	5,216,631	6/1993	Sliwa, Jr.	365	174	
V	BP	5,233,554	8/1993	Conley et al.	364	822	
/JO/	BQ	5,239,504	8/1993	Brady et al.	365	· 157	

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	Document No.	Date	Country	Class	Sub Class	Translation Yes No
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LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION . DISCLOSURE STATEMENT	First Named Invent	cor:
	Ear C. Johns	
	Filing Date	Group Art:
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U.S. PATENT DOCUMENTS

Exam: Init		Document No.	Date	Name	Class	Sub Class	Filing Date If Appropriate
/JO/	CA	5,261,055	11/1993	Moran et al.	395	275	
	СВ	5,291,584	3/1994	Challa et al.	395	500	
	СС	5,307,311	4/1994	Sliwa, Jr.	365	174	
	CD	5,343,426	8/1994	Cassidy et al.	365	189.02	•
	CE	5,359,565	10/1994	Takatori	365	105	
	CF	5,359,726	10/1994	Thomas	395	500	
	CG	5,361,238	11/1994	Owechko	365	234	
	СН	5,372,859	12/1994	Thakoor	427	551	
	CI	5,379,266	1/1995	Russell	365	234	
	CJ	5,388,267	2/1995	Chan et al.	395	700	
•	СК	5,410,680	4/1995	Challa et al.	395	500	
	CL	5,423,054	6/1995	Schmidt et al.	395	800	
	СМ	5,426,075	6/1995	Perino et al.	437	235	
	CN	5,426,769	6/1995	Pawloski	395	500	
	со	5,428,417	6/1995	Lichtenstein	353	122	
V_{-}	CP	5,432,950	7/1995	Sibigtroth	395	425	
/JO/	CQ	6,515,957	2/2003	Newns et al.	369.	126	

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LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT U.S. PATENT DOCUMENTS Ear C. Johns Filing Date Group Art: Herewith Herewith	FORM 1	PTO-14	149 .			•	Atty.	Docket	No.:	Appl. No.:	
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/JO/ microscopy", by Y. Cho et al., <u>APPLIED PHYSICS LETTERS</u> , Vol. 81, No. 23, pgs. 4401-4403, 2 December 2002.	/JO/		"Tbit/inch ² ferroelectric data storage based on scanning nonlinear dielectric microscopy", by Y. Cho et al., <u>APPLIED PHYSICS LETTERS</u> , Vol. 81, No. 23, pgs. 4401-4403, 2 December 2002.								
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